

Supplementary Information for

## Unique dynamics and exocytosis properties of GABAergic synaptic vesicles revealed by three-dimensional single vesicle tracking

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Fig. S1. VGAT-QD preferentially labels GABAergic synaptic vesicles in cultured hippocampal neurons. (A-B) Representative fluorescence images of GABAergic presynaptic terminals labeled with CypHer5E-conjugated antibodies against the luminal domain of VGAT (VGAT-CypHer5E, red) and synaptic vesicles loaded with QDs conjugated to antibodies against the luminal domain of VGAT (VGAT-QD, green; A) or antibodies against the luminal domain of Syt1 (Syt1-QD, green; B). Scale bars: 3  $\mu$ m. (C) Percentage of colocalization between VGAT-CypHer5E–labeled boutons and either VGAT-QD–loaded vesicles (61 ± 3.4 % (N = 13 images)) or Syt1-QD–loaded vesicles (12 ± 1.4 % (N = 13)). Error bars show SEM. \*\*\*P < 0.001 (Student's *t*-test).



Fig. S2. Cumulative distribution of net displacement of VGAT-QD–loaded and Syt1-QD–loaded synaptic vesicles undergoing either full-collapse fusion or kiss-and-run fusion. (A) Cumulative distribution of net displacement of VGAT-QD–loaded vesicles and Syt1-QD–loaded vesicles undergoing full-collapse fusion. The net displacement of VGAT-labeled synaptic vesicles undergoing full-collapse fusion (VGAT FCF) was not significantly different from that of Syt1-labeled vesicles undergoing full-collapse fusion (Syt1 FCF) ( $260 \pm 46$  nm (n = 28 vesicles) vs.  $302 \pm 43$  nm (n = 36), respectively; P > 0.4, K-S test). (B) Cumulative distribution of net displacement of VGAT-QD–loaded vesicles and Syt1-QD–loaded vesicles undergoing kiss-and-run fusion. The net displacement of VGAT-labeled synaptic vesicles undergoing kiss-and-run fusion (VGAT K&R) was not significantly different from that of Syt1-labeled vesicles undergoing kiss-and-run fusion (VGAT K&R) was not significantly different from that of Syt1-labeled vesicles undergoing kiss-and-run fusion (VGAT K&R) was not significantly different from that of Syt1-labeled vesicles undergoing kiss-and-run fusion (VGAT K&R) was not significantly different from that of Syt1-labeled vesicles undergoing kiss-and-run fusion (Syt1 K&R) ( $231 \pm 27$  nm (n = 52) vs.  $143 \pm 28$  nm (n = 13), respectively; P > 0.3, K-S test). NS: not significant.



**Fig. S3. Normalized fluorescence traces of non-releasing VGAT-QD–loaded vesicles.** Five individual traces are shown in gray, and the average trace is shown with a red line. A blue horizontal bar represents electrical stimuli (10 Hz) for 120 s starting at 20 s.